

# NCV7349

## High Speed Low Power CAN Transceiver

### Description

The NCV7349 CAN transceiver is the interface between a controller area network (CAN) protocol controller and the physical bus. The transceiver provides differential transmit capability to the bus and differential receive capability to the CAN controller.

The NCV7349 is a new addition to the CAN high-speed transceiver family complementing NCV734x CAN family and previous generations of CAN transceivers such as AMIS42665, AMIS3066x, etc.

Due to the wide common-mode voltage range of the receiver inputs and other design features, the NCV7349 is able to reach outstanding levels of electromagnetic susceptibility (EMS). Similarly, very low electromagnetic emission (EME) is achieved by the excellent matching of the output signals.

### Features

- Compatible with the ISO 11898-5 Standard
- High Speed (up to 1 Mbps)
- V<sub>IO</sub> Pin on NCV7349-3 Version Allowing Direct Interfacing with 3 V to 5 V Microcontrollers
- Very Low Current Standby Mode with Wake-up via the Bus
- Low Electromagnetic Emission (EME) and Extremely High Electromagnetic Immunity
- Very Low EME without Common-mode (CM) Choke
- No Disturbance of the Bus Lines with an Un-powered Node
- Transmit Data (TxD) Dominant Time-out Function
- Under All Supply Conditions the Chip Behaves Predictably
- Very High ESD Robustness of Bus Pins, >10 kV System ESD Pulses
- Thermal Protection
- Bus Pins Short Circuit Proof to Supply Voltage and Ground
- Bus Pins Protected Against Transients in an Automotive
- These are Pb-Free Devices

### Quality

- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

### Typical Applications

- Automotive
- Industrial Networks

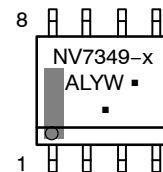


ON Semiconductor®

<http://onsemi.com>



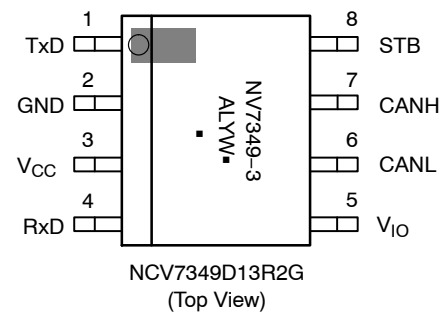
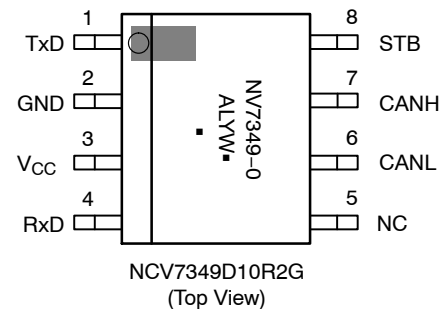
### MARKING DIAGRAM



NV7349-x = Specific Device Code  
x = 0 or 3  
A = Assembly Location  
L = Wafer Lot  
Y = Year  
W = Work Week  
▪ = Pb-Free Package

(\*Note: Microdot may be in either location)

### PIN ASSIGNMENT



### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

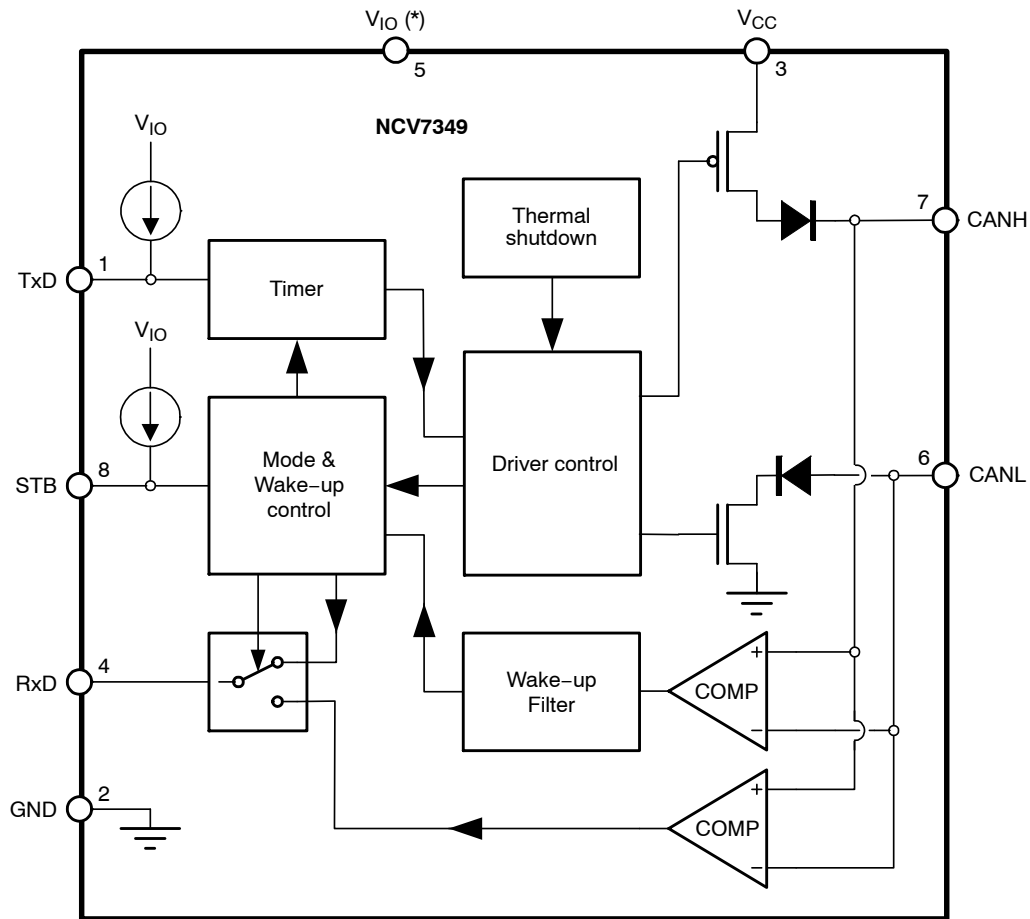
# NCV7349

**Table 1. KEY TECHNICAL CHARACTERISTICS AND OPERATING RANGES**

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	Power supply voltage	(Note 1)	4.75 (4.5)	5.25 (5.5)	V
$V_{UV}$	Undervoltage detection voltage on pin Vcc		2	4	V
$V_{CANH}$	DC voltage at pin CANH	$0 < V_{CC} < 5.5$ V; no time limit	-50	+50	V
$V_{CANL}$	DC voltage at pin CANL	$0 < V_{CC} < 5.5$ V; no time limit	-50	+50	V
$V_{CANH,Lmax}$	DC voltage at pin CANH and CANL during load dump condition	$0 < V_{CC} < 5.5$ V, less than one second	-	+58	V
$V_{ESD}$	Electrostatic discharge voltage	IEC 61000-4-2 at pins CANH and CANL	-15	15	kV
$V_{O(dif)(bus\_dom)}$	Differential bus output voltage in dominant state	$45 \Omega < R_{LT} < 65 \Omega$	1.5	3	V
CM-range	Input common-mode range for comparator	Guaranteed differential receiver threshold and leakage current	-35	+35	V
$C_{load}$	Load capacitance on IC outputs		-	15	pF
$t_{pd0}$	Propagation delay (NCV7349-0 version)	See Figure 7	-	245	ns
$t_{pd3}$	Propagation delay (NCV7349-3 version)	See Figure 7	-	250	ns
$T_J$	Junction temperature		-40	150	°C

1. In the range of 4.5 V to 4.75 V and from 5.25 V to 5.5 V the chip is fully functional; some parameters may be outside of the specification.

## BLOCK DIAGRAM



\*On NCV7349-0 version pin 5 is not connected.  $V_{IO}$  supply is provided by  $V_{CC}$ .

**Figure 1. Block Diagram**

# NCV7349

## TYPICAL APPLICATION

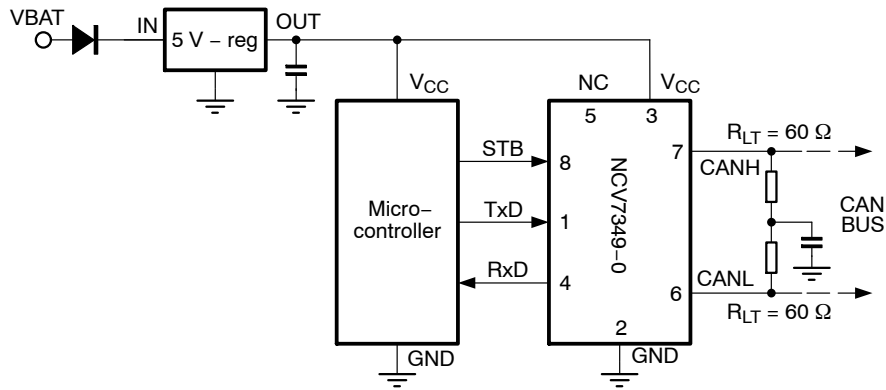


Figure 2. Application Diagram, NCV7349-0

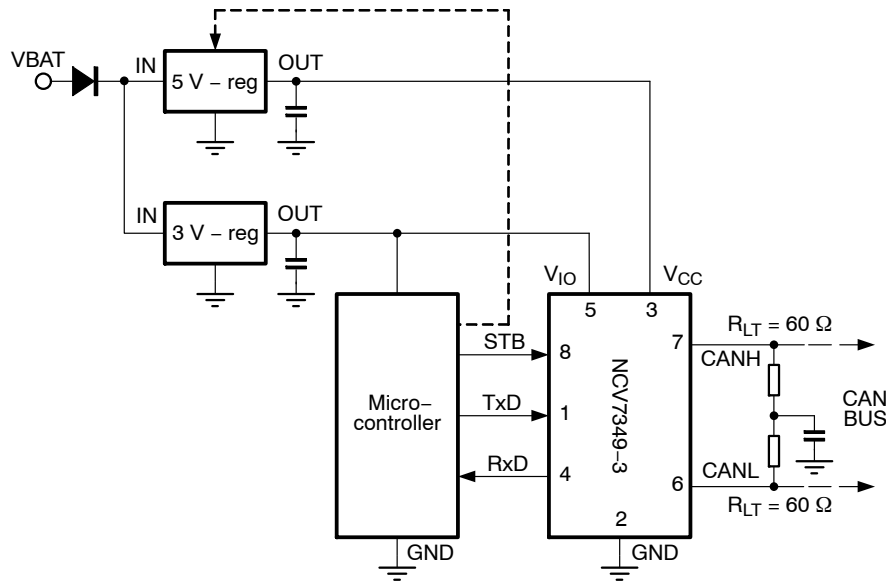


Figure 3. Application Diagram, NCV7349-3

Table 2. PIN FUNCTION DESCRIPTION

Pin	Name	Description
1	TxD	Transmit data input; low input → Driving dominant on bus; internal pull-up current
2	GND	Ground
3	V <sub>CC</sub>	Supply voltage
4	RxD	Receive data output; bus in dominant → low output
5	NC	Not connected. On NCV7349-0 only.
5	V <sub>IO</sub>	Input / Output pins supply voltage. On NCV7349-3 only
6	CANL	Low-level CAN bus line (low in dominant mode)
7	CANH	High-level CAN bus line (high in dominant mode)
8	STB	Standby mode control input; internal pull-up current

FUNCTIONAL DESCRIPTION

NCV7349 has two versions which differ from each other only by function of pin 5.

NCV7349-0: Pin 5 is not connected. (see Figure 2)

NCV7349-3: Pin 5 is V<sub>IO</sub> pin, which is supply pin for transceiver digital inputs/output (supplying pins TxD, RxD, STB) The V<sub>IO</sub> pin should be connected to microcontroller supply pin. By using V<sub>IO</sub> supply pin shared with microcontroller the I/O levels between microcontroller and transceiver are properly adjusted. This adjustment allows in applications with microcontroller supply down to 3 V to easy communicate with the transceiver. (See Figure 3)

Operating Modes

NCV7349 provides two modes of operation as illustrated in Table 3. These modes are selectable through pin STB.

Table 3. OPERATING MODES

Pin STB	Mode	Pin RxD	
		Low	High
Low	Normal	Bus dominant	Bus recessive
High	Standby	Wake-up request detected	No wake-up request detected

Normal Mode

In the normal mode, the transceiver is able to communicate via the bus lines. The signals are transmitted and received to the CAN controller via the pins TxD and RxD. The slopes on the bus lines outputs are optimized to give low EME.

Standby Mode

In standby mode both the transmitter and receiver are disabled and a very low-power differential receiver monitors the bus lines for CAN bus activity. The bus lines are terminated to ground and supply current is reduced to a minimum, typically 10 μA. When a wake-up request is detected by the low-power differential receiver, the signal is first filtered and then verified as a valid wake signal after a time period of t<sub>wake</sub>, the RxD pin is driven low by the transceiver to inform the controller of the wake-up request.

V<sub>IO</sub> Supply pin

The V<sub>IO</sub> pin available only on NCV7349-3 version should be connected to microcontroller supply pin. By using V<sub>IO</sub> supply pin shared with microcontroller the I/O levels between microcontroller and transceiver are properly adjusted. See Figure 3. Pin V<sub>IO</sub> on NCV7349-3 does not provide the internal supply voltage for low-power differential receiver of the transceiver. Detection of wake-up request is not possible when there is no supply voltage on pin V<sub>CC</sub>.

Wake-up

When a valid wake-up (dominant state longer than t<sub>wake</sub>) is received during the standby mode the RxD pin is driven low. The wake-up detection is not latched: RxD returns to High state after t<sub>dwakedr</sub> when the bus signal is released back to recessive – see Figure 4.

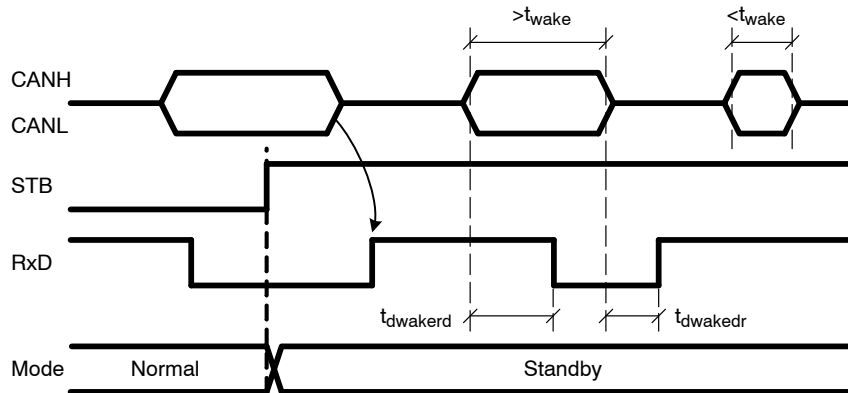


Figure 4. NCV7349 Wake-up Behavior

## Over-temperature Detection

A thermal protection circuit protects the IC from damage by switching off the transmitter if the junction temperature exceeds a value of approximately 170°C. Because the transmitter dissipates most of the power, the power dissipation and temperature of the IC is reduced. All other IC functions continue to operate. The transmitter off-state resets when the temperature decreases below the shutdown threshold and pin TxD goes high. The thermal protection circuit is particularly needed when a bus line short circuits.

## TxD Dominant Time-out Function

A TxD dominant time-out timer circuit prevents the bus lines being driven to a permanent dominant state (blocking all network communication) if pin TxD is forced permanently low by a hardware and/or software application failure. The timer is triggered by a negative edge on pin TxD. If the duration of the low-level on pin TxD exceeds the internal timer value  $t_{\text{dom(TxD)}}$ , the transmitter is disabled, driving the bus into a recessive state. The timer is reset by a positive edge on pin TxD.

This TxD dominant time-out time ( $t_{\text{dom(TxD)}}$ ) defines the minimum possible bit rate to 15 kbps.

## Fail Safe Features

A current-limiting circuit protects the transmitter output stage from damage caused by accidental short circuit to either positive or negative supply voltage, although power dissipation increases during this fault condition.

Undervoltage on  $V_{\text{CC}}$  pin prevents the chip sending data on the bus when there is not enough  $V_{\text{CC}}$  supply voltage. After supply is recovered TxD pin must be first released to high to allow sending dominant bits again. Recovery time from undervoltage detection is equal to  $t_{\text{d(stb-nm)}}$  time.

$V_{\text{IO}}$  supply dropping below  $V_{\text{UVDVIO}}$  undervoltage detection level will cause the transceiver to disengage from the bus (no bus loading) until the  $V_{\text{IO}}$  voltage recovers (NCV7349-3 version only).

The pins CANH and CANL are protected from automotive electrical transients (according to ISO 7637; see Figure 7). Pins TxD and STB are pulled high internally should the input become disconnected. Pins TxD, STB and RxD will be floating, preventing reverse supply should the  $V_{\text{IO}}$  supply be removed.

**ELECTRICAL CHARACTERISTICS**

**Definitions**

All voltages are referenced to GND (pin 2). Positive currents flow into the IC. Sinking current means the current is flowing into the pin; sourcing current means the current is flowing out of the pin.

**ABSOLUTE MAXIMUM RATINGS**

**Table 4. ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Conditions	Min.	Max.	Unit
V <sub>SUP</sub>	Supply voltage V <sub>CC</sub> , V <sub>IO</sub>		-0.3	+6	V
V <sub>CANH</sub>	DC voltage at pin CANH	0 < V <sub>CC</sub> < 5.5 V; no time limit	-50	+50	V
V <sub>CANL</sub>	DC voltage at pin CANL	0 < V <sub>CC</sub> < 5.5 V; no time limit	-50	+50	V
V <sub>IO</sub>	DC voltage at pin TxD, RxD, STB		-0.3	6	V
V <sub>esd</sub>	Electrostatic discharge voltage at all pins	(Note 2) (Note 3)	-6 500	6 500	kV V
	Electrostatic discharge voltage at CANH and CANL pins	(Note 4)	-10	10	kV
V <sub>schaft</sub>	Transient voltage	(Note 5)	-150	100	V
Latch-up	Static latch-up at all pins	(Note 6)		150	mA
T <sub>stg</sub>	Storage temperature		-55	+150	°C
T <sub>A</sub>	Ambient temperature		-40	+125	°C
T <sub>J</sub>	Maximum junction temperature		-40	+170	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Standardized human body model electrostatic discharge (ESD) pulses in accordance to EIA-JESD22. Equivalent to discharging a 100 pF capacitor through a 1.5 kΩ resistor.
- Standardized charged device model ESD pulses when tested according to ESD-STM5.3.1-1999.
- System human body model electrostatic discharge (ESD) pulses. Equivalent to discharging a 150 pF capacitor through a 330 Ω resistor referenced to GND.
- Pulses 1, 2a, 3a and 3b according to ISO 7637 part 3. Indicative values based on structural similarity to NCV7340 where results were verified by external test house.
- Static latch-up immunity: Static latch-up protection level when tested according to EIA/JESD78.

**Table 5. THERMAL CHARACTERISTICS**

Symbol	Parameter	Conditions	Value	Unit
R <sub>θJA_1</sub>	Thermal Resistance Junction-to-Air, 1S0P PCB (Note 7)	Free air	125	K/W
R <sub>θJA_2</sub>	Thermal Resistance Junction-to-Air, 2S2P PCB (Note 8)	Free air	75	K/W

- Test board according to EIA/JEDEC Standard JESD51-3, signal layer with 10% trace coverage
- Test board according to EIA/JEDEC Standard JESD51-7, signal layers with 10% trace coverage

**ELECTRICAL CHARACTERISTICS**

**Table 6. CHARACTERISTICS** (V<sub>CC</sub> = 4.75 V to 5.25 V; V<sub>IO</sub> = 2.8 V to 5.5 V (NCV7349-3 only); T<sub>J</sub> = -40 to +150°C; R<sub>LT</sub> = 60 Ω unless specified otherwise. On chip versions without V<sub>IO</sub> pin, reference voltage for all digital inputs and outputs is V<sub>CC</sub> instead of V<sub>IO</sub>.)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>SUPPLY (Pin V<sub>CC</sub>)</b>						
I <sub>CC</sub>	Supply current	Dominant; V <sub>TxD</sub> = 0 V Recessive; V <sub>TxD</sub> = V <sub>IO</sub>	-	48 6	75 10	mA
I <sub>CCS</sub>	Supply current in standby mode	T <sub>J</sub> ≤ 100°C, (Note 9)	-	10	15	μA
V <sub>UVDVCC</sub>	Undervoltage detection voltage on V <sub>CC</sub> pin		2	3	4	V

- Values based on design and characterization, not tested in production

# NCV7349

**Table 6. CHARACTERISTICS** ( $V_{CC} = 4.75\text{ V to }5.25\text{ V}$ ;  $V_{IO} = 2.8\text{ V to }5.5\text{ V}$  (NCV7349-3 only);  $T_J = -40\text{ to }+150^\circ\text{C}$ ;  $R_{LT} = 60\ \Omega$  unless specified otherwise. On chip versions without  $V_{IO}$  pin, reference voltage for all digital inputs and outputs is  $V_{CC}$  instead of  $V_{IO}$ .)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>SUPPLY (pin <math>V_{IO}</math>) on NCV7349-3 Version Only</b>						
$V_{IO}$	Supply voltage on pin $V_{IO}$		2.8	–	5.5	V
$I_{IOS}$	Supply current on pin $V_{IO}$ in standby mode	Standby mode	–	1	–	$\mu\text{A}$
$I_{IONM}$	Supply current on pin $V_{IO}$ in normal mode	Dominant; $V_{TXD} = 0\text{ V}$ Recessive; $V_{TXD} = V_{IO}$	–	–	1 0.2	mA
$V_{UVDVIO}$	Undervoltage detection voltage on $V_{IO}$ pin		1.3	–	2.7	V
<b>TRANSMITTER DATA INPUT (Pin <math>TxD</math>)</b>						
$V_{IH}$	High-level input voltage	Output recessive	2.0	–	$V_{IO}$	V
$V_{IL}$	Low-level input voltage	Output dominant	–0.3	–	+0.8	V
$I_{IH}$	High-level input current	$V_{TXD} = V_{IO}$	–5	0	+5	$\mu\text{A}$
$I_{IL}$	Low-level input current	$V_{TXD} = 0\text{ V}$	–350	–200	–	$\mu\text{A}$
$C_i$	Input capacitance	(Note 9)	–	5	10	pF
<b>TRANSMITTER MODE SELECT (Pin <math>STB</math>)</b>						
$V_{IH}$	High-level input voltage	Standby mode	2.0	–	$V_{IO}$	V
$V_{IL}$	Low-level input voltage	Normal mode	–0.3	–	+0.8	V
$I_{IH}$	High-level input current	$V_{STB} = V_{IO}$	–5	0	+5	$\mu\text{A}$
$I_{IL}$	Low-level input current	$V_{STB} = 0\text{ V}$	–10	–4	–1	$\mu\text{A}$
$C_i$	Input capacitance	(Note 9)	–	5	10	pF
<b>RECEIVER DATA OUTPUT (Pin <math>RxD</math>)</b>						
$I_{OH}$	High-level output current	Normal mode, $V_{RxD} = V_{IO} - 0.4\text{ V}$	–1	–0.4	–0.1	mA
$I_{OL}$	Low-level output current	$V_{RxD} = 0.4\text{ V}$	1.6	6	12	mA
$V_{OH}$	High-level output voltage	Standby mode, $I_{RxD} = -100\ \mu\text{A}$	$V_{IO} - 1.1$	$V_{IO} - 0.7$	$V_{IO} - 0.4$	V
<b>BUS LINES (Pins <math>CANH</math> and <math>CANL</math>)</b>						
$V_{o(\text{reces})}$ (norm)	Recessive bus voltage on pins $CANH$ and $CANL$	$V_{TXD} = V_{IO}$ ; no load; normal mode	2.0	2.5	3.0	V
$V_{o(\text{reces})}$ (stby)	Recessive bus voltage on pins $CANH$ and $CANL$	$V_{TXD} = V_{IO}$ ; no load; standby mode	–100	0	100	mV
$I_{o(\text{reces})}$ ( $CANH$ )	Recessive output current at pin $CANH$	$-35\text{ V} < V_{CANH} < +35\text{ V}$ ; $0\text{ V} < V_{CC} < 5.25\text{ V}$	–2.5	–	+2.5	mA
$I_{o(\text{reces})}$ ( $CANL$ )	Recessive output current at pin $CANL$	$-35\text{ V} < V_{CANL} < +35\text{ V}$ ; $0\text{ V} < V_{CC} < 5.25\text{ V}$	–2.5	–	+2.5	mA
$I_{LI}$ ( $CANH$ )	Input leakage current to pin $CANH$	$0\ \Omega < R(V_{CC}\text{ to GND}) < 1\ \text{M}\Omega$ $V_{CANL} = V_{CANH} = 5\text{ V}$	–10	0	10	$\mu\text{A}$
$I_{LI}$ ( $CANL$ )	Input leakage current to pin $CANL$	$0\ \Omega < R(V_{CC}\text{ to GND}) < 1\ \text{M}\Omega$ $V_{CANL} = V_{CANH} = 5\text{ V}$	–10	0	10	$\mu\text{A}$
$V_{o(\text{dom})}$ ( $CANH$ )	Dominant output voltage at pin $CANH$	$V_{TXD} = 0\text{ V}$	3.0	3.6	4.25	V
$V_{o(\text{dom})}$ ( $CANL$ )	Dominant output voltage at pin $CANL$	$V_{TXD} = 0\text{ V}$	0.5	1.4	1.75	V
$V_{o(\text{dif})}$ (bus_dom)	Differential bus output voltage ( $V_{CANH} - V_{CANL}$ )	$V_{TXD} = 0\text{ V}$ ; dominant; $45\ \Omega < R_{LT} < 65\ \Omega$	1.5	2.25	3.0	V
$V_{o(\text{dif})}$ (bus_rec)	Differential bus output voltage ( $V_{CANH} - V_{CANL}$ )	$V_{TXD} = V_{IO}$ ; recessive; no load	–120	0	+50	mV
$I_{o(\text{sc})}$ ( $CANH$ )	Short circuit output current at pin $CANH$	$V_{CANH} = 0\text{ V}$ ; $V_{TXD} = 0\text{ V}$	–100	–70	–45	mA

9. Values based on design and characterization, not tested in production

# NCV7349

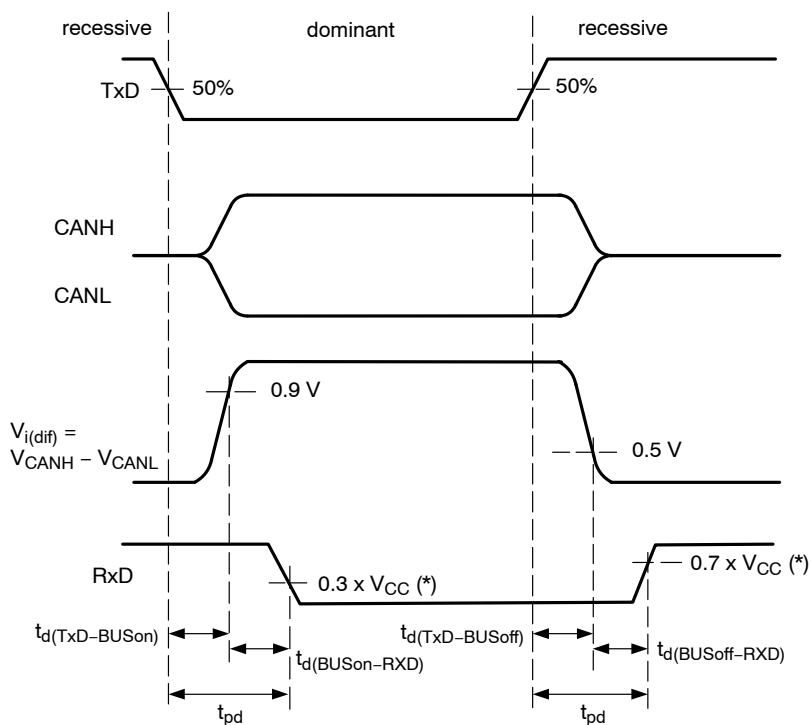
**Table 6. CHARACTERISTICS** ( $V_{CC} = 4.75\text{ V to }5.25\text{ V}$ ;  $V_{IO} = 2.8\text{ V to }5.5\text{ V}$  (NCV7349-3 only);  $T_J = -40\text{ to }+150^\circ\text{C}$ ;  $R_{LT} = 60\ \Omega$  unless specified otherwise. On chip versions without  $V_{IO}$  pin, reference voltage for all digital inputs and outputs is  $V_{CC}$  instead of  $V_{IO}$ .)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
<b>BUS LINES (Pins CANH and CANL)</b>						
$I_{O(sc)}$ (CANL)	Short circuit output current at pin CANL	$V_{CANL} = 36\text{ V}$ ; $V_{TxD} = 0\text{ V}$	45	70	100	mA
$V_{i(dif)R}$ (th)	Differential receiver threshold voltage – Dominant to Recessive (see Figure 6)	$-2\text{ V} < V_{CANL} < +7\text{ V}$ ; $-2\text{ V} < V_{CANH} < +7\text{ V}$	0.5	0.6	0.7	V
$V_{i(dif)D}$ (th)	Differential receiver threshold voltage – Recessive to Dominant (see Figure 6)	$-2\text{ V} < V_{CANL} < +7\text{ V}$ ; $-2\text{ V} < V_{CANH} < +7\text{ V}$	0.7	0.8	0.9	V
$V_{ihcmR}$ (dif) (th)	Differential receiver threshold voltage – Dominant to Recessive (see Figure 6)	$-35\text{ V} < V_{CANL} < +35\text{ V}$ ; $-35\text{ V} < V_{CANH} < +35\text{ V}$	0.4	–	0.8	V
$V_{ihcmD}$ (dif) (th)	Differential receiver threshold voltage – Recessive to Dominant (see Figure 6)	$-35\text{ V} < V_{CANL} < +35\text{ V}$ ; $-35\text{ V} < V_{CANH} < +35\text{ V}$	0.6	–	1	V
$V_{ihcmD12}$ (dif) (th)	Differential receiver threshold voltage – Both transitions (see Figure 6)	$-12\text{ V} < V_{CANL} < +12\text{ V}$ ; $-12\text{ V} < V_{CANH} < +12\text{ V}$	0.5	–	0.9	V
$V_{i(dif)}$ (hys)	Differential receiver input voltage hysteresis	$-2\text{ V} < V_{CANL} < +7\text{ V}$ ; $-2\text{ V} < V_{CANH} < +7\text{ V}$	100	200	300	mV
$V_{i(dif)}$ (th)_STDBY	Differential receiver threshold voltage in standby mode	$-12\text{ V} < V_{CANL} < +12\text{ V}$ ; $-12\text{ V} < V_{CANH} < +12\text{ V}$	0.4	0.8	1.15	V
$R_{i(cm)}$ (CANH)	Common-mode input resistance at pin CANH		15	26	37	k $\Omega$
$R_{i(cm)}$ (CANL)	Common-mode input resistance at pin CANL		15	26	37	k $\Omega$
$R_{i(cm)}$ (m)	Matching between pin CANH and pin CANL common mode input resistance	$V_{CANH} = V_{CANL}$	–3	0	+3	%
$R_{i(dif)}$	Differential input resistance		25	50	75	k
$C_{i(CANH)}$	Input capacitance at pin CANH	$V_{TxD} = V_{IO}$ ; (Note 9)	–	–	30	pF
$C_{i(CANL)}$	Input capacitance at pin CANL	$V_{TxD} = V_{IO}$ ; (Note 9)	–	–	30	pF
$C_{i(dif)}$	Differential input capacitance	$V_{TxD} = V_{IO}$ ; (Note 9)	–	3.75	10	pF
<b>THERMAL SHUTDOWN</b>						
$T_{J(sd)}$	Shutdown junction temperature	Junction temperature rising	150	170	185	$^\circ\text{C}$
<b>TIMING CHARACTERISTICS (see Figure 5 and Figure 8)</b>						
$t_d(TxD-BUSon)$	Delay TxD to bus active	$C_i = 100\text{ pF}$ between CANH to CANL	–	50	–	ns
$t_d(TxD-BUSoff)$	Delay TxD to bus inactive	$C_i = 100\text{ pF}$ between CANH to CANL	–	60	–	ns
$t_d(BUSon-RxD)$	Delay bus active to RxD	$C_{RxD} = 15\text{ pF}$	–	60	–	ns
$t_d(BUSoff-RxD)$	Delay bus inactive to RxD	$C_{RxD} = 15\text{ pF}$	–	60	–	ns
$t_{pd}$	Propagation delay TxD to RxD (NCV7349-0 version)	$C_i = 100\text{ pF}$ between CANH to CANL	–	125	245	ns
	Propagation delay TxD to RxD (NCV7349-3 version)	$C_i = 100\text{ pF}$ between CANH to CANL	–	130	250	ns
$t_d(stb-nm)$	Delay standby mode to normal mode		5	8	20	$\mu\text{s}$
$t_{wake}$	Dominant time for wake-up via bus		0.5	2.5	5	$\mu\text{s}$
$t_{dwakerd}$	Delay to flag wake event (recessive to dominant transitions)	Valid bus wake-up event, $C_{RxD} = 15\text{ pF}$	1	4.5	10	$\mu\text{s}$
$t_{dwakedr}$	Delay to flag wake event (dominant to recessive transitions)	Valid bus wake-up event, $C_{RxD} = 15\text{ pF}$	0.5	3.3	7	$\mu\text{s}$
$t_{dom}(TxD)$	TxD dominant time for time-out	$V_{TxD} = 0\text{ V}$	1.2	2.6	4	ms

9. Values based on design and characterization, not tested in production



MEASUREMENT SETUPS AND DEFINITIONS



\*On NCV7349-3  $V_{CC}$  is replaced by  $V_{IO}$

Figure 5. Transceiver Timing Diagram

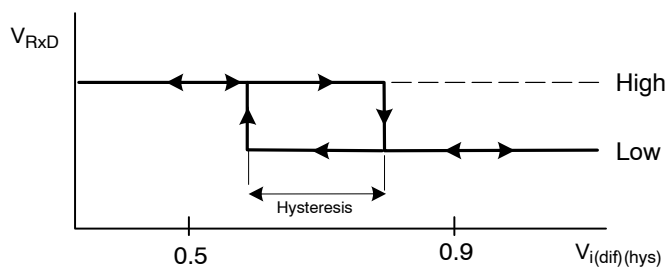
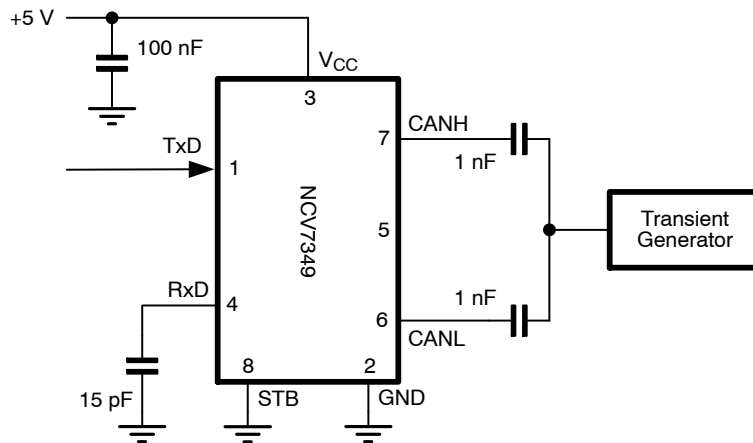
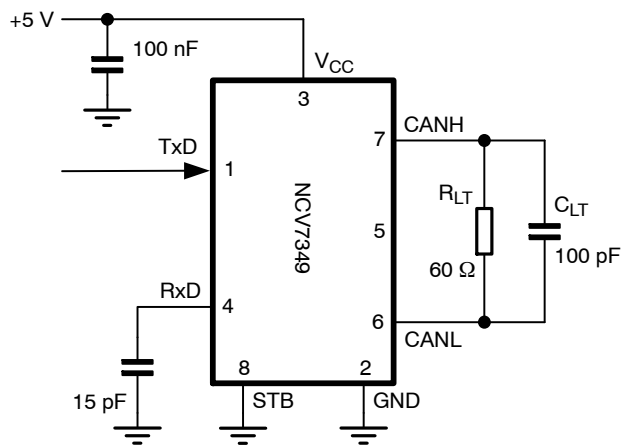


Figure 6. Hysteresis of the Receiver

## NCV7349



**Figure 7. Test Circuit for Automotive Transients**



**Figure 8. Test Circuit for Timing Characteristics**

### DEVICE ORDERING INFORMATION

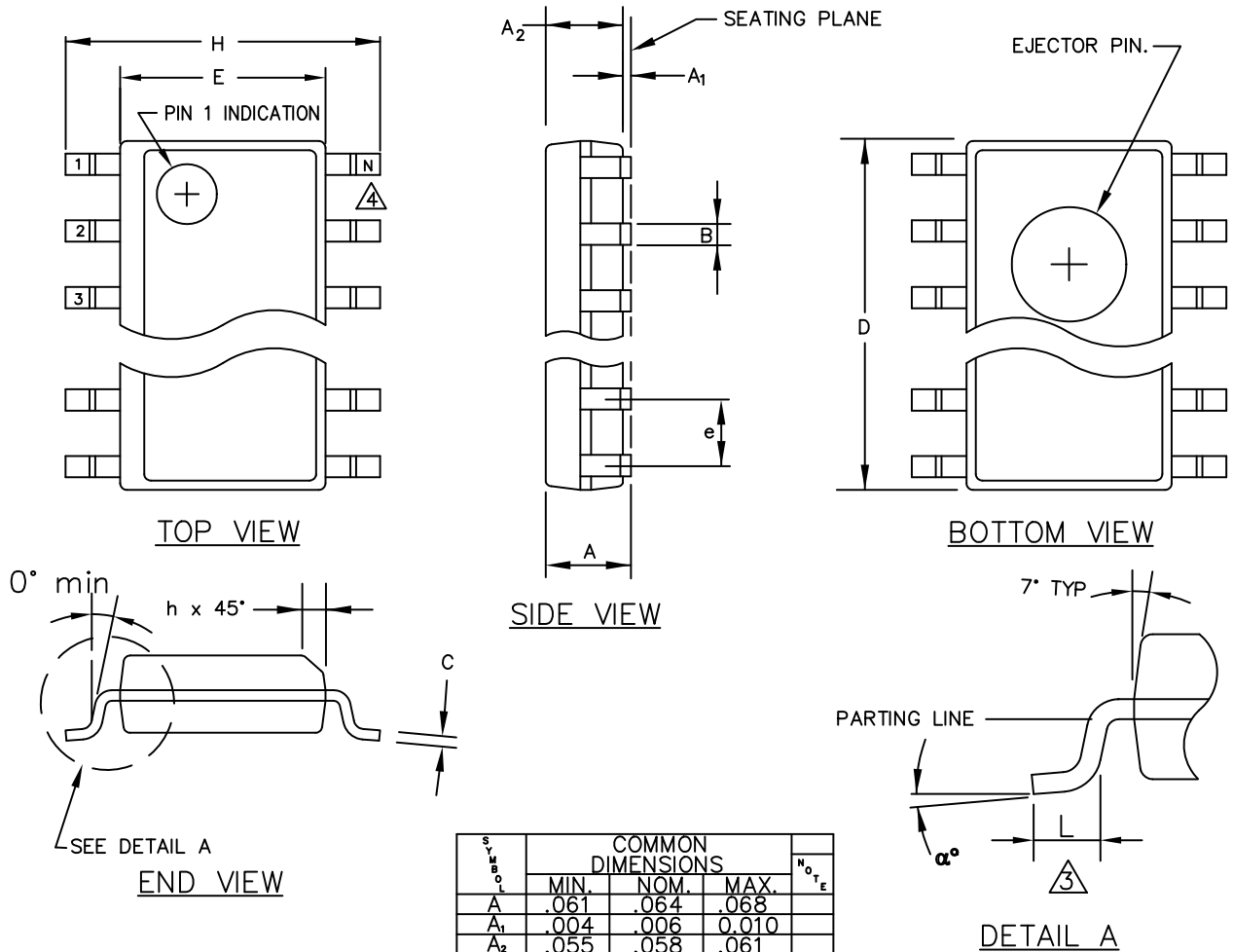
Part Number	Description	Temperature Range	Package	Shipping †
NCV7349D10R2G	High Speed Low Power CAN Transceiver for the Japanese Market	-40°C to +125°C	SOIC 150 8 GREEN (Matte Sn, JEDEC MS-012) (Pb-Free)	3000 / Tape & Reel
NCV7349D13R2G	High Speed Low Power CAN Transceiver for the Japanese Market with V <sub>IO</sub> pin (available in 2015)			

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCV7349

## PACKAGE DIMENSIONS


SOIC 8  
CASE 751AZ  
ISSUE O



SYMBOL	COMMON DIMENSIONS			NOTE
	MIN.	NOM.	MAX.	
A	.061	.064	.068	
A <sub>1</sub>	.004	.006	0.010	
A <sub>2</sub>	.055	.058	.061	
B	.0138	.016	.020	
C	.0075	.008	.0098	
D	SEE VARIATIONS			1
E	.150	.155	.157	
e	.050 BSC			
H	.230	.236	.244	
h	.010	.013	.016	
L	.016	.025	.035	
N	SEE VARIATIONS			2
α°	0°	5°	8°	

VARIATIONS				
	1			2
	D			N
NOTE	MIN.	NOM.	MAX.	
AA	.189	.194	.196	8
AB	.337	.342	.344	14
AC	.386	.391	.393	16

1. ALL DIMENSIONS ARE IN MILLIMETERS.

**ON Semiconductor** and  are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Literature Distribution Center for ON Semiconductor  
P.O. Box 5163, Denver, Colorado 80217 USA  
**Phone:** 303-675-2175 or 800-344-3860 Toll Free USA/Canada  
**Fax:** 303-675-2176 or 800-344-3867 Toll Free USA/Canada  
**Email:** [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**N. American Technical Support:** 800-282-9855 Toll Free  
USA/Canada  
**Europe, Middle East and Africa Technical Support:**  
Phone: 421 33 790 2910  
**Japan Customer Focus Center**  
Phone: 81-3-5817-1050

**ON Semiconductor Website:** [www.onsemi.com](http://www.onsemi.com)  
**Order Literature:** <http://www.onsemi.com/orderlit>  
For additional information, please contact your local  
Sales Representative



## Стандарт Электрон Связь

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

### Наши контакты:

**Телефон:** +7 812 627 14 35

**Электронная почта:** [sales@st-electron.ru](mailto:sales@st-electron.ru)

**Адрес:** 198099, Санкт-Петербург,  
Промышленная ул, дом № 19, литера Н,  
помещение 100-Н Офис 331